

UT54ACS14/UT54ACTS14

Radiation-Hardened

Hex Inverting Schmitt Triggers

FEATURES

- 1.2μ radiation-hardened CMOS
 - Latchup immune
- High speed
- Low power consumption
- Single 5 volt supply
- Available QML Q or V processes
- Flexible package
 - 14-pin DIP
 - 14-lead flatpack

DESCRIPTION

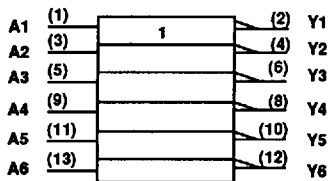
The UT54ACS14 and the UT54ACTS14 are hex inverters. The circuits perform the Boolean function $Y = \bar{A}$.

The devices are characterized over full military temperature range of -55°C to +125°C.

FUNCTION TABLE

INPUT	OUTPUT
A	Y
H	L
L	H

LOGIC SYMBOL

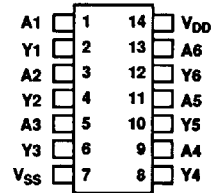


Note:

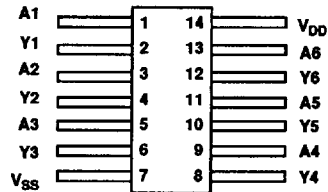
1. Logic symbol in accordance with ANSI/IEEE standard 91-1984 and IEC Publication 617-12.

PINOUTS

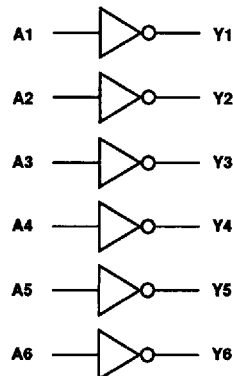
14-Pin DIP
Top View



14-Lead Flatpack
Top View



LOGIC DIAGRAM



RADIATION HARDNESS SPECIFICATIONS¹

PARAMETER	LIMIT	UNITS
Total Dose	1.0E6	rads(Si)
SEU & SEL Threshold ²	80	MeV-cm ² /mg
Neutron Fluence	1.0E14	n/cm ²

Notes:

1. Logic will not latchup during radiation exposure within the limits defined in the table.
2. Device storage elements are immune to SEU affects.

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	LIMIT	UNITS
V _{DD}	Supply voltage	-0.3 to 7.0	V
V _{IO}	Voltage any pin	-.3 to V _{DD} +.3	V
T _{STG}	Storage Temperature range	-65 to +150	°C
T _J	Maximum junction temperature	+175	°C
T _{LS}	Lead temperature (soldering 5 seconds)	+300	°C
Θ _{JC}	Thermal resistance junction to case	20	°C/W
I _I	DC input current	±10	mA
P _D	Maximum power dissipation	1	W

Note:

1. Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, functional operation of the device at these or any other conditions beyond limits indicated in the operational sections is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMIT	UNITS
V _{DD}	Supply voltage	4.5 to 5.5	V
V _{IN}	Input voltage any pin	0 to V _{DD}	V
T _C	Temperature range	-55 to + 125	°C

UT54ACS14/UT54ACTS14

DC ELECTRICAL CHARACTERISTICS ⁷

($V_{DD} = 5.0V \pm 10\%$; $V_{SS} = 0V$ ⁶, $-55^{\circ}C < T_C < +125^{\circ}C$)

SYMBOL	PARAMETER	CONDITION	MIN	MAX	UNIT
V_{IL}	Low-level input voltage ¹ ACTS ACS			0.5 .3 V_{DD}	V
V_{IH}	High-level input voltage ¹ ACTS ACS		.5 V_{DD} .7 V_{DD}		V
V_{T+}	Schmitt Trigger, positive going ¹ threshold ACTS ACS		0.9 2.0	2.25 .7 V_{DD}	V
V_{T-}	Schmitt Trigger, negative going ¹ threshold ACTS ACS		0.5 .3 V_{DD}	1.6 2.6	V
V_H	Schmitt Trigger, typical range of hysteresis ² ACTS ACS		0.4 0.6	0.9 1.5	V
I_{IN}	Input leakage current ACTS/ACS	$V_{IN} = V_{DD}$ or V_{SS}	-1	1	μA
V_{OL}	Low-level output voltage ³ ACTS ACS	$I_{OL} = 8.0mA$ $I_{OL} = 100\mu A$		0.40 0.25	V
V_{OH}	High-level output voltage ³ ACTS ACS	$I_{OH} = -8.0mA$ $I_{OH} = -100\mu A$	.7 V_{DD} $V_{DD}-0.25$		V
I_{OS}	Short-circuit output current ^{2,4} ACTS/ACS	$V_O = V_{DD}$ and V_{SS}	-200	200	mA
P_{total}	Power dissipation ^{8,9}	$C_L = 50pF$		1.8	mW/ MHz
I_{DDQ}	Quiescent Supply Current	$V_{DD} = 5.5V$		10	μA
C_{IN}	Input capacitance ⁵	$f = 1MHz @ 0V$		15	pF
C_{OUT}	Output capacitance ⁵	$f = 1MHz @ 0V$		15	pF

Notes:

- Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions: $V_{IH} = V_{IH(min)} + 20\%$, -0% ; $V_{IL} = V_{IL(max)} + 0\%$, -50% , as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to $V_{IH(min)}$ and $V_{IL(max)}$.
- Supplied as a design limit but not guaranteed or tested.
- Per MIL-M-38510, for current density $\leq 5.0E5$ amps/cm², the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765 pF MHz.
- Not more than one output may be shorted at a time for maximum duration of one second.
- Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and V_{SS} at frequency of 1MHz and a signal amplitude of 50mV rms maximum.
- Maximum allowable relative shift equals 50mV.
- All specifications valid for radiation dose $\leq 1E6$ rads(Si).
- Power does not include power contribution of any TTL output sink current.
- Power dissipation specified per switching output.

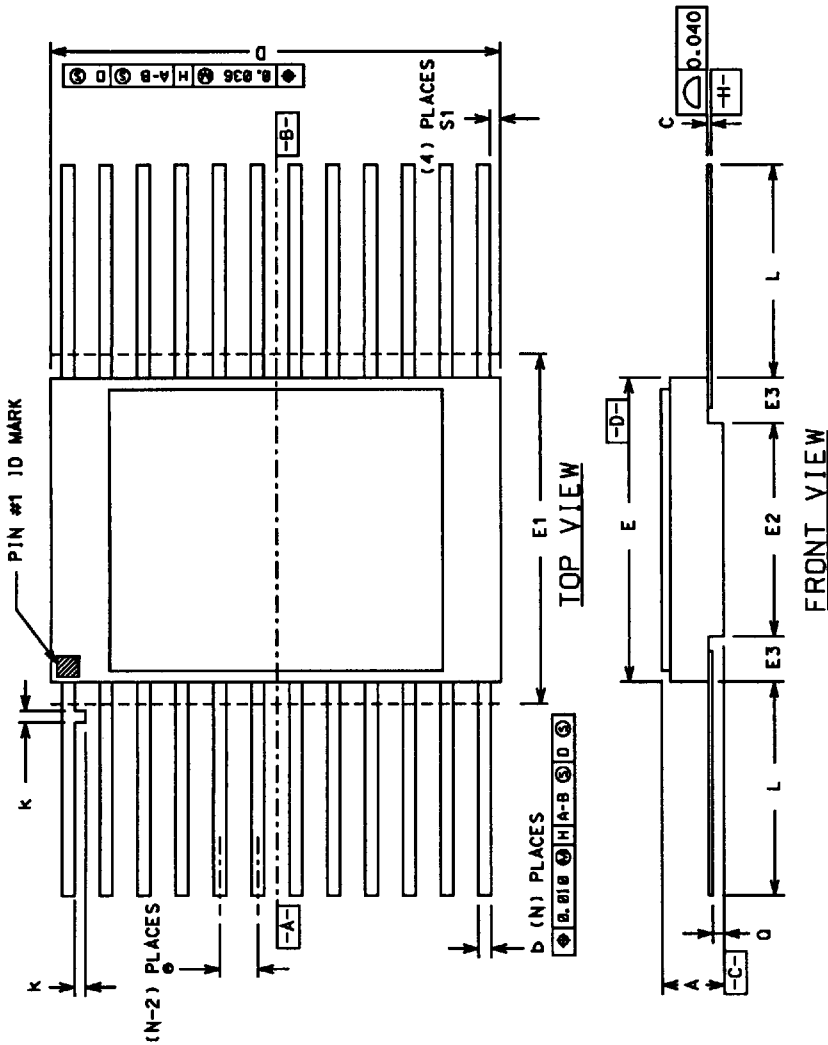
AC ELECTRICAL CHARACTERISTICS ²(V_{DD} = 5.0V ±10%; V_{SS} = 0V ¹, -55°C < T_C < +125°C)

SYMBOL	PARAMETER	MINIMUM	MAXIMUM	UNIT
t _{PHL}	Input to Yn	2	14	ns
t _{PLH}	Input to Yn	2	13	ns

Notes:

1. Maximum allowable relative shift equals 50mV.
2. All specifications valid for radiation dose ≤1E6 rads(Si)

Flatpack Packages



PKG CONF IG	LEAD COUNT	MIL-STD 1836 DWG CONF B	DIMENSION SYMBOLS												
			A	b	c	D	E	E1	E2	E3	e	k	L	O	S1
-03	14	F-2A	0.115	0.022	0.009	0.390	0.260	0.290	----	----	----	0.050	0.370	0.045	----
			0.045	0.015	0.004	0.235	0.235	----	0.130	0.030	BSC	0.015	0.270	0.026	0.005
-04	16	F-5A	0.115	0.022	0.009	0.440	0.285	0.315	----	----	----	0.050	0.370	0.045	----
			0.045	0.015	0.004	0.245	0.245	----	0.130	0.030	BSC	0.015	0.250	0.026	0.005
-05	20	F-9A	0.115	0.022	0.009	0.540	0.300	0.330	----	----	----	0.050	0.370	0.045	----
			0.045	0.015	0.004	0.245	0.245	----	0.130	0.030	BSC	0.008	0.250	0.026	0.000